imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MCH3383

Power MOSFET –12V, 69mΩ, –3.5A, Single P-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

Features

- Low On-Resistance
- 0.9V drive
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

Typical Applications

- LED Current Balance SW
- Load Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	-12	V
Gate to Source Voltage	VGSS	±5	V
Drain Current (DC)	ID	-3.5	А
Drain Current (Pulse) PW ≤ 10µs, duty cycle ≤ 1%	IDP	-14	А
Power Dissipation When mounted on ceramic substrate ($900mm^2 \times 0.8mm$)	PD	1.0	W
Junction Temperature	Tj	150	°C
Operating Temperature	Topr	-5 to +150	°C
Storage Temperature	Tstg	-55 to +150	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² \times 0.8mm)	R _{θJA}	125	°C/W



ON Semiconductor®

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VDSS	R _{DS} (on) Max	ID Max
-12V	69mΩ@ –2.5V	
	98mΩ@ –1.8V	-3 5A
	173mΩ@ –1.2V	-3.5A
	500mΩ@ –0.9V	

ELECTRICAL CONNECTION P-Channel



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

Parameter	Symbol	Symbol Conditions	Value			Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-12			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-12V, V _{GS} =0V			-10	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±4V, V _{DS} =0V			±10	μA
Gate Threshold Voltage	VGS(th)	V _{DS} =-6V, I _D =-1mA	-0.3		-0.8	V
Forward Transconductance	9FS	V _{DS} =-6V, I _D =-1.5A		5.3		S
	R _{DS} (on)1	ID=-1.5A, VGS=-2.5V		57	69	mΩ
Static Drain to Source On-State	R _{DS} (on)2	ID=-0.7A, VGS=-1.8V		75	98	mΩ
Resistance	R _{DS} (on)3	ID=-0.3A, VGS=-1.2V		115	173	mΩ
	R _{DS} (on)4	ID=-50mA, VGS=-0.9V		250	500	mΩ
Input Capacitance	Ciss			1010		pF
Output Capacitance	Coss	V _{DS} =–6V, f=1MHz		130		pF
Reverse Transfer Capacitance	Crss			85		pF
Turn-ON Delay Time	t _d (on)			9.9		ns
Rise Time	tr			49		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		109		ns
Fall Time	tf			65		ns
Total Gate Charge	Qg			6.2		nC
Gate to Source Charge	Qgs	V _{DS} =-6V, V _{GS} =-2.5V, I _D =-3.5A		1.6		nC
Gate to Drain "Miller" Charge	Qgd			1.1		nC
Forward Diode Voltage	V _{SD}	IS=-3.5A, VGS=0V		-0.83	-1.2	V

ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 2)

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit





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MCH3383



PACKAGE DIMENSIONS

unit : mm

SC-70FL / MCPH3 CASE 419AQ ISSUE O



ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)	
MCH3383-TL-H	22	SC-70FL / MCPH3		
MCH3383-TL-W	QQ (Pb-Free / Haloger		3,000 / Tape & Reel	

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the MCH3383 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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